

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r m e s s a g e s	E r r o r s
1	BRS	L1	12993	(etch\$3 or pattern\$3 or deposit\$3) same ((first or second or two) adj (resist or photoresist or mask))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:18			0
2	BRS	L8	8337	1 and @pd<=20000515	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:43			0
3	BRS	L22	2682	8 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:09			0
4	BRS	L15	515	8 and 216/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:42			0
5	BRS	L36	42	(MIM or capacitor) and 15	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:02			0
6	BRS	L29	415	(MIM or capacitor) and 22	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:07			0
7	BRS	L43	16	36 not 29	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:07			0
8	BRS	L50	389	29 not 36	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:07			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r m e s s a g e s	E r r o r s
9	BRS	L57	8171	(etch\$3 or pattern\$3 or deposit\$3) same (((first and second) or two) adj (resist or photoresist or mask))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:23			0
10	BRS	L64	24	57 and (((MIM or "metal insulator metal") adj capacitor) or MIMCAP)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 19:31			0
11	BRS	L71	607	(((MIM or "metal insulator metal") adj capacitor) or MIMCAP)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:08			0
12	BRS	L78	130	(((MIM or "metal insulator metal") adj capacitor) or MIMCAP) same (rie or ("reactive ion" adj etch\$3) or etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:35			0
13	BRS	L85	59	78 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:14			0
14	BRS	L92	261	(((MIM or "metal insulator metal") adj capacitor) or MIMCAP) and (rie or ("reactive ion" adj etch\$3) or etch\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:39			0
15	BRS	L99	118	92 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:42			0
16	BRS	L106	2754	((positive and negative) with (resist or photoresist)) same etch\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:50			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r D e f i n i t i o n	E r r o r s
17	BRS	L120	681	106 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:43			0
18	BRS	L113	337	106 and 216/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:43			0
19	BRS	L134	429	120 and @pd<=20000515	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:43			0
20	BRS	L127	289	113 and @pd<=20000515	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:44			0
21	BRS	L141	3	((first) adj (negative adj (resist or photoresist))) and ((second) adj (positive adj (resist or photoresist)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/01 20:55			0